NSN 5961-01-152-9017

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View Online at https://aerobasegroup.com/nsn/5961-01-152-9017

Inclosure Material:

Metal

Overall Length:

Between 0.480 inches and 0.535 inches

End Application:

Radar set an/sps-4 (v)

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case and quality assurance level tx

Overall Width Across Flats:

Between 0.847 inches and 0.875 inches

Thread Size:

0.250 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

150.0 collector to base voltage/static/emitter open and 120.0 collector to emitter voltage/static/base open and 10.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

50.00 amperes source cutoff current

Power Rating Per Characteristic:

350.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

Special Features:

Junction pattern arrangement: npn

Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Thread Series Designator:

Unf

Terminal Type And Quantity:

1 wire hook and 2 tab, solder lug

Specification Data:

81349-mil-s-19500/447 government specification

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0

